

Strong Coupling between a photon and a hole spin in silicon

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Eoin Kelly
22/08/2022

Abstract

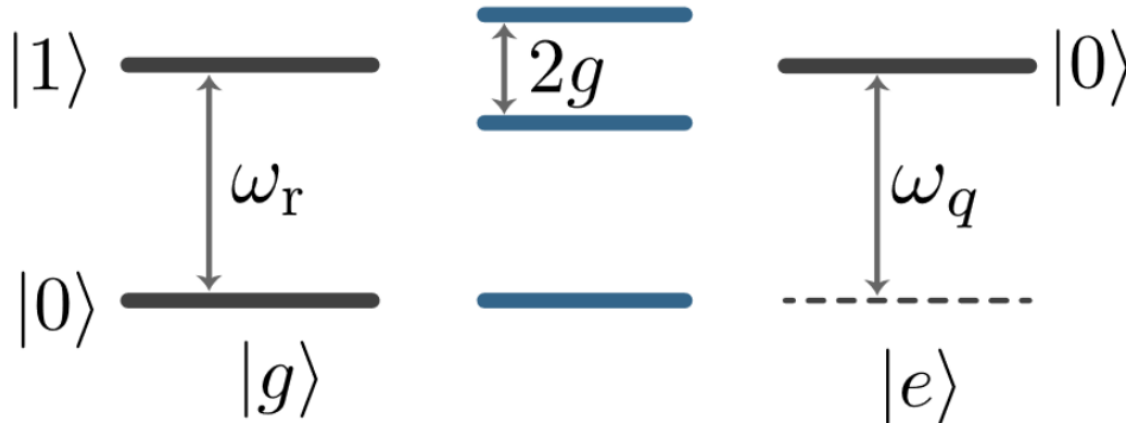
Spins in semiconductor quantum dots constitute a promising platform for scalable quantum information processing¹. Coupling them strongly to the photonic modes of superconducting microwave resonators would enable fast non-demolition readout and long-range, on-chip connectivity, well beyond nearest-neighbor quantum interactions²⁻⁴. Here we demonstrate strong coupling between a microwave photon in a superconducting resonator and a hole spin in a silicon-based double quantum dot issued from a foundry-compatible MOS fabrication process. By leveraging the strong spin-orbit interaction intrinsically present in the valence band of silicon^{5,6}, we achieve a spin-photon coupling rate as high as 330 MHz largely exceeding the combined spin-photon decoherence rate. This result, together with the recently demonstrated long coherence of hole spins in silicon⁷, opens a new realistic pathway to the development of circuit quantum electrodynamics with spins in semiconductor quantum dots.



Background

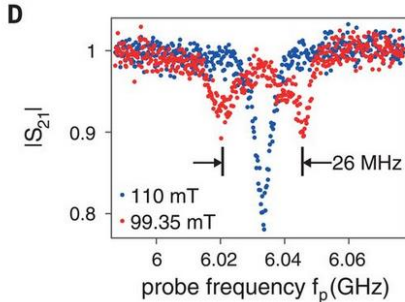
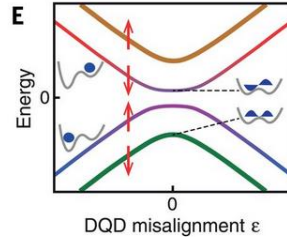
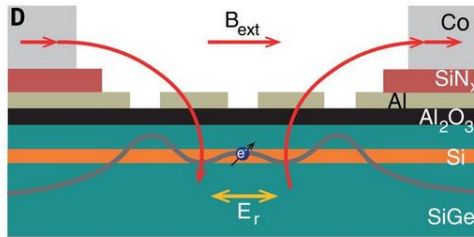
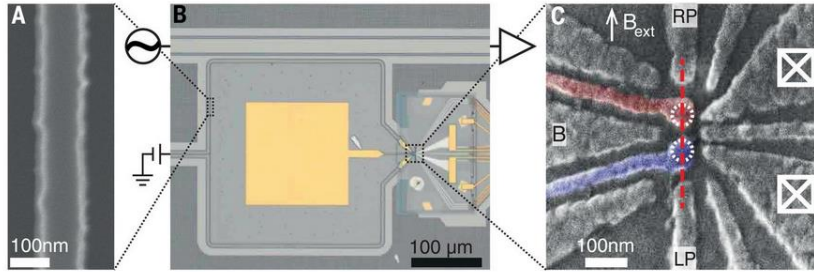
$$\hat{H}_{\text{JC}} = \hbar\omega_r \hat{a}^\dagger \hat{a} + \frac{\hbar\omega_q}{2} \hat{\sigma}_z + \hbar g (\hat{a}^\dagger \hat{\sigma}_- + \hat{a} \hat{\sigma}_+)$$

- Strong coupling between qubit and resonator when $\omega_r = \omega_q$
- Formation of hybridized states separated in energy by coupling strength g
- Signature: vacuum Rabi splitting ($g > \kappa, \gamma$)

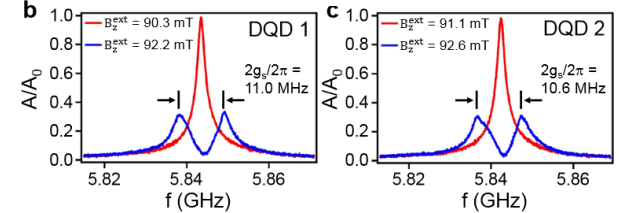
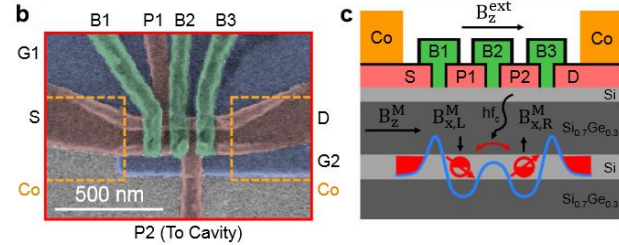
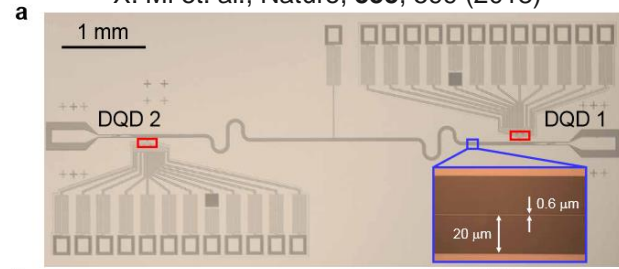


Background

N. Samkharadze et. al., Science, **359**, 6380 (2018)

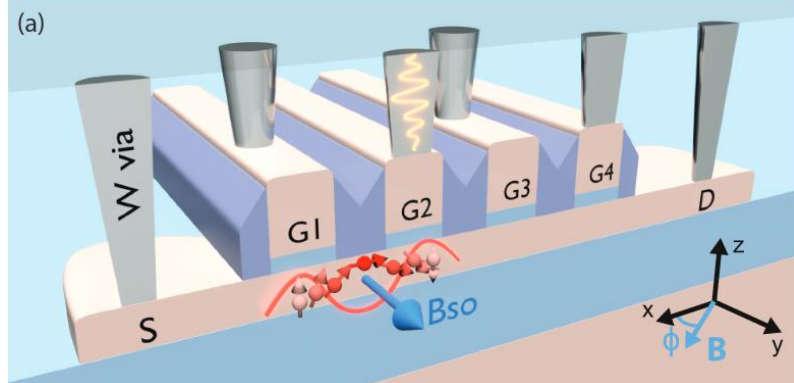
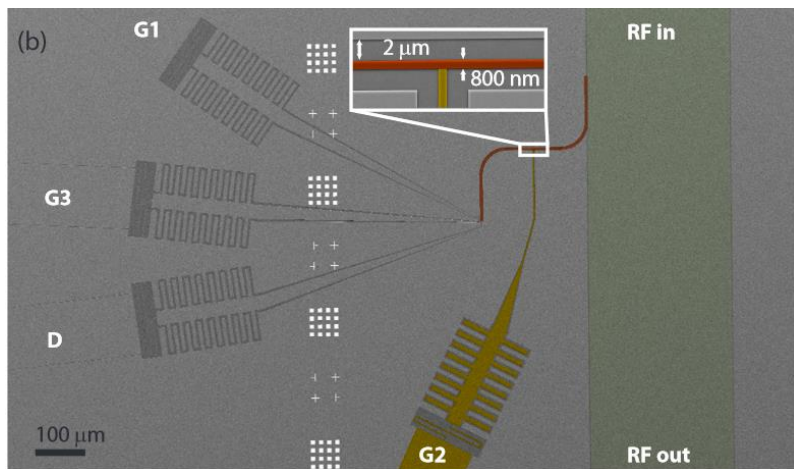


X. Mi et. al., Nature, **555**, 599 (2018)



- Strong coupling previously demonstrated for electrons in Si/SiGe
- Micromagnet required for coupling spin to E-field of resonator
- **Here:** use intrinsically present spin-orbit interaction for holes in Si

Device Architecture

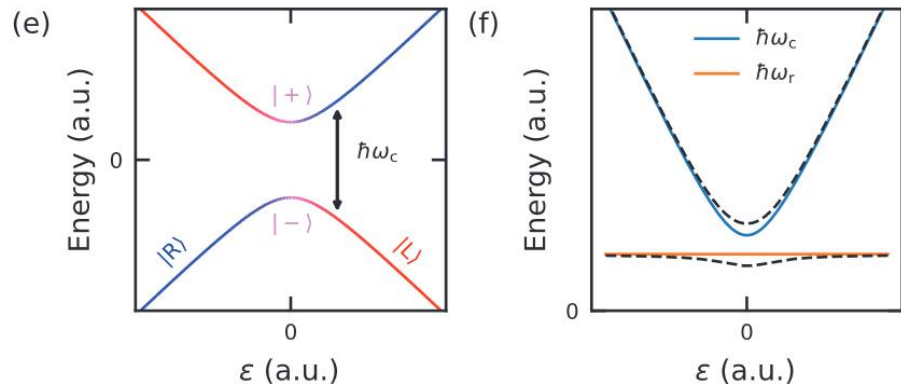
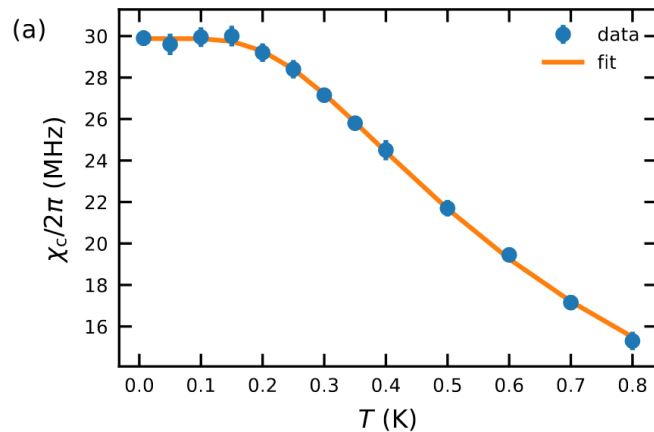
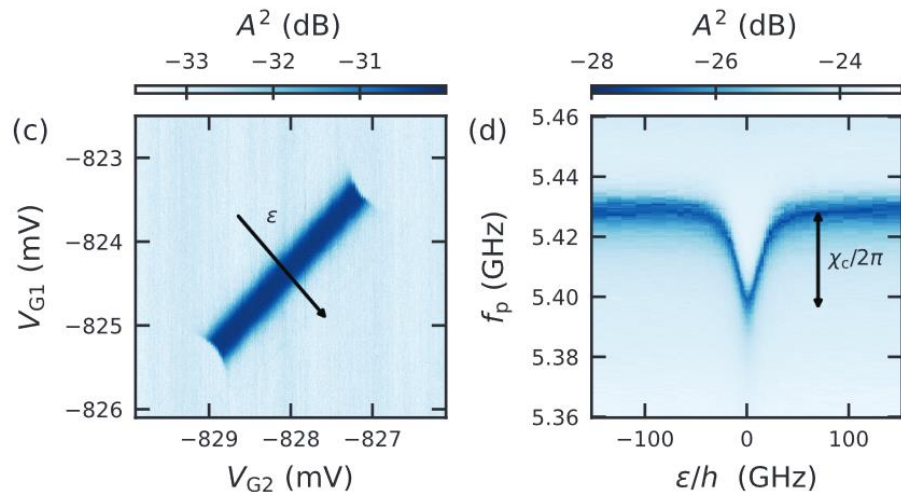


- Resonator and DC lines fabricated from NbN on packaging oxide
- $\lambda/2$ CPW hanger resonator with bias tap
- DC lines with LC lowpass filters $f_c = 1.2$ GHz ($L = 123$ nH, $C = 0.134$ pF)
- Connections to NbN circuitry through W interconnects
- G3, G4 shorted at device level
- Source hard grounded to NbN ground plane
- DQD defined under G1, G2

- $f_r = 5.428$ GHz
- $Q_{\text{int}} = 530$
- $Q_{\text{ext}} = 1550$



Resonator – DQD Charge Coupling

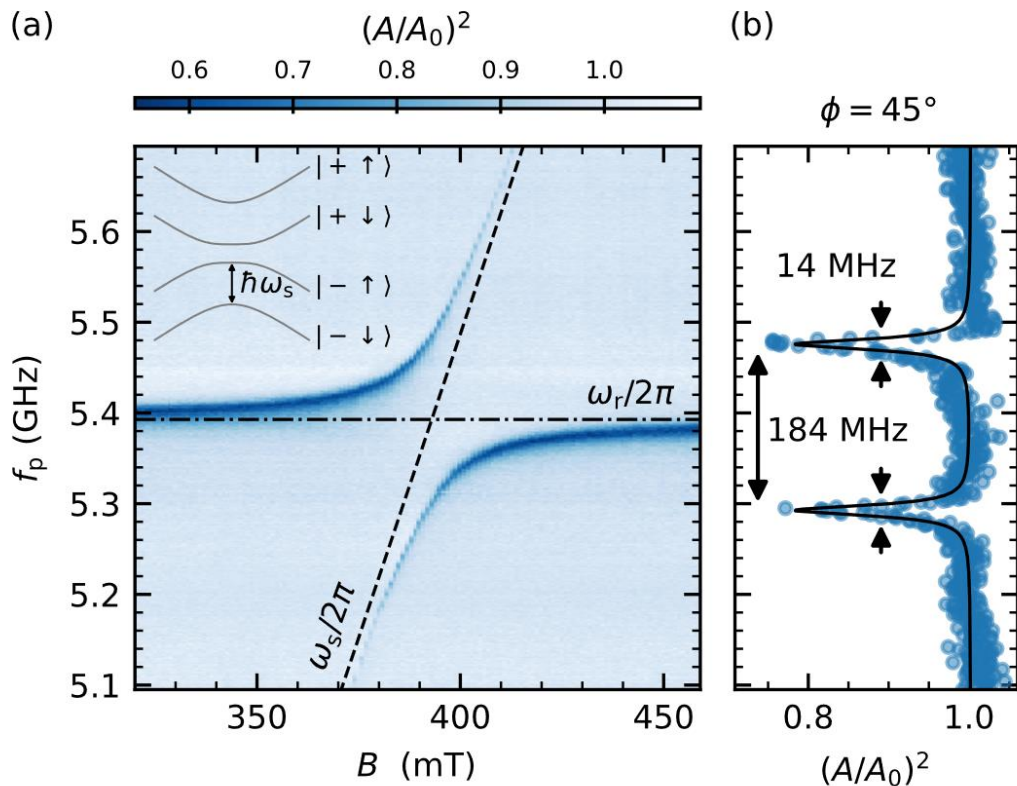


From $\chi_c(T)$:

$$\frac{g_c}{2\pi} = 513 \text{ MHz}$$

$$\frac{t_c}{2\pi} = 9.57 \text{ GHz}$$


Strong Hole Spin-Photon Coupling



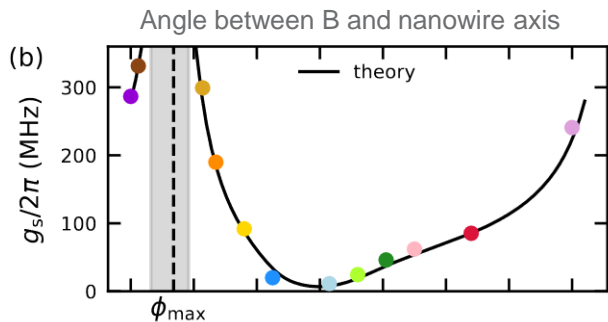
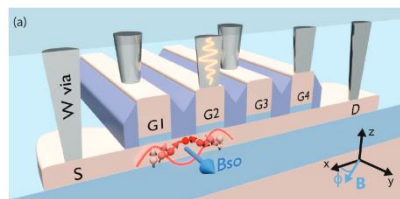
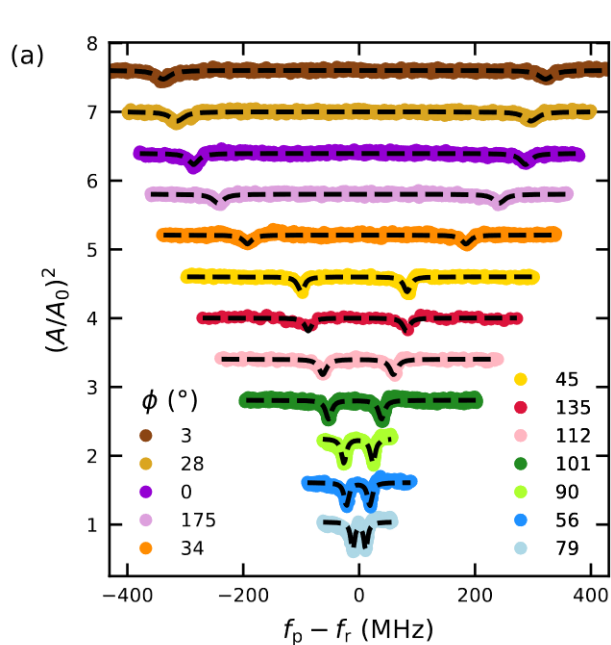
$$\text{linewidth: } \frac{1}{2} \left(\gamma_s + \frac{\kappa}{2} \right) / 2\pi = 7 \text{ MHz}$$

$$\text{Cavity decay rate: } \kappa / 2\pi = 14 \text{ MHz}$$

$$\text{Extracted spin decoherence: } \gamma_s / 2\pi = 7 \text{ MHz}$$



Spin-Photon Coupling vs. Magnetic Field Orientation



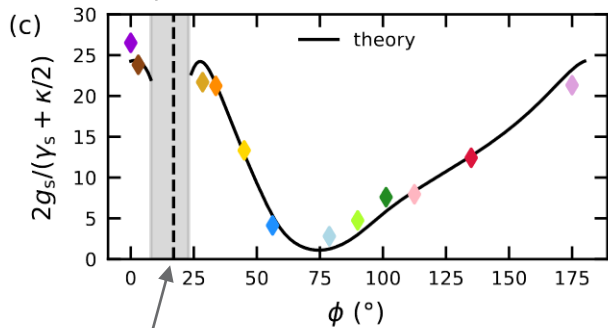
Maximum $g_s=330$ MHz at 3°

Minimum $g_s=10$ MHz at 79°

Model:

$$g_s \propto g_c |(\bar{g}\mathbf{B}) \times (\bar{g}\mathbf{B}_{so})|$$

\bar{g} is average g-tensor of the two dots



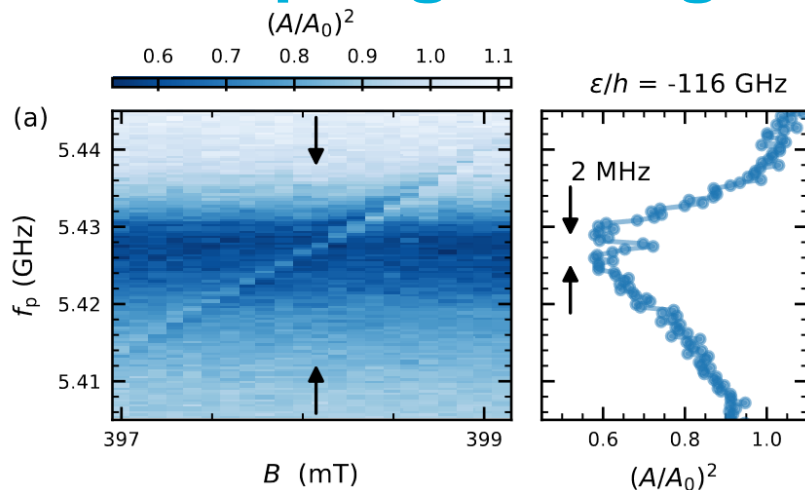
g_s near maximum when $\mathbf{B} \perp \mathbf{B}_{so}$
(not exactly orthogonal due to g-matrix anisotropy)

\mathbf{B}_{so} mostly in-plane perpendicular to nanowire

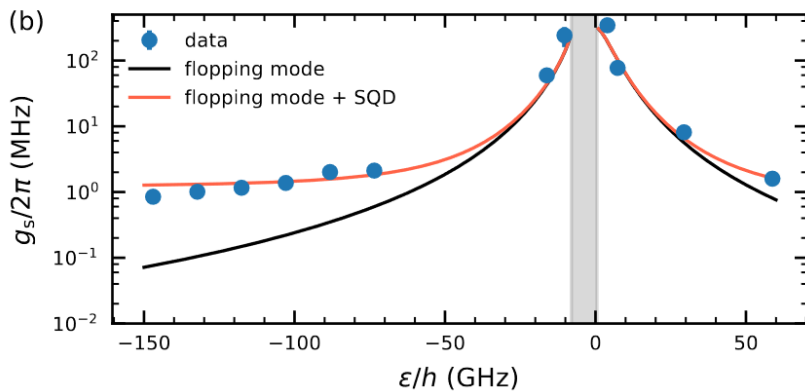
B-field > 1 T required



Spin-Photon Coupling in Single Dot Limit



$$g_s^{(R)} = 1.16 \text{ MHz}$$
$$g_s^{(L)} = 0.66 \text{ MHz}$$

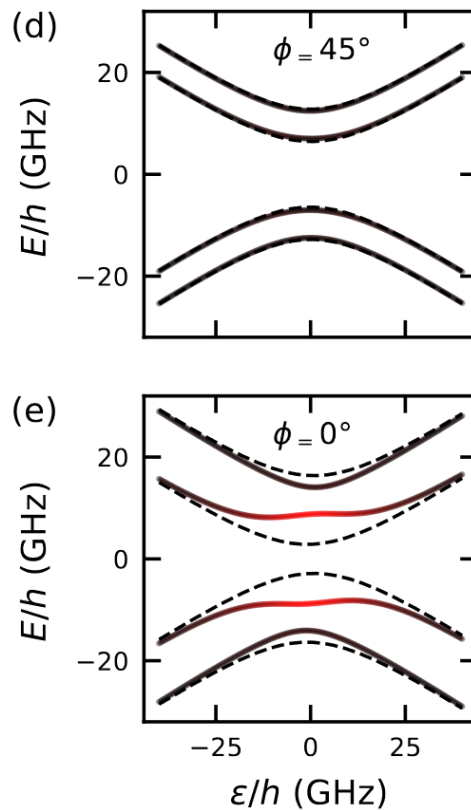


Conclusion / Future work

- Spin-photon coupling largely exceeds results for electrons in Si
- Modified layout and resonator optimization to increase charge photon coupling and reduce resonator losses (aim: < 1 MHz)
- Implementation of spin-photon coupling schemes relying on charge noise sweet spots

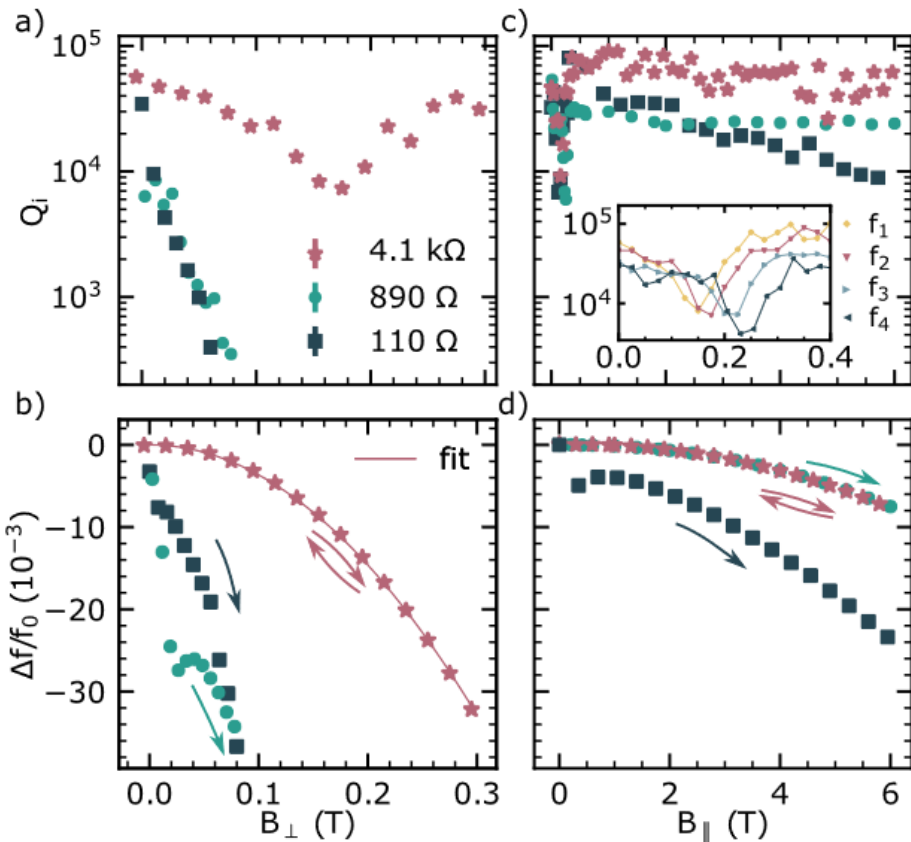
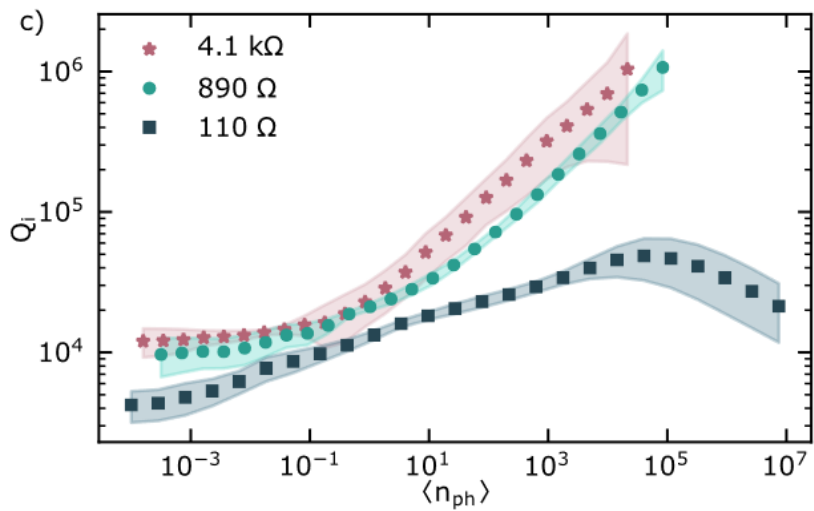


Spin-Charge Mixing

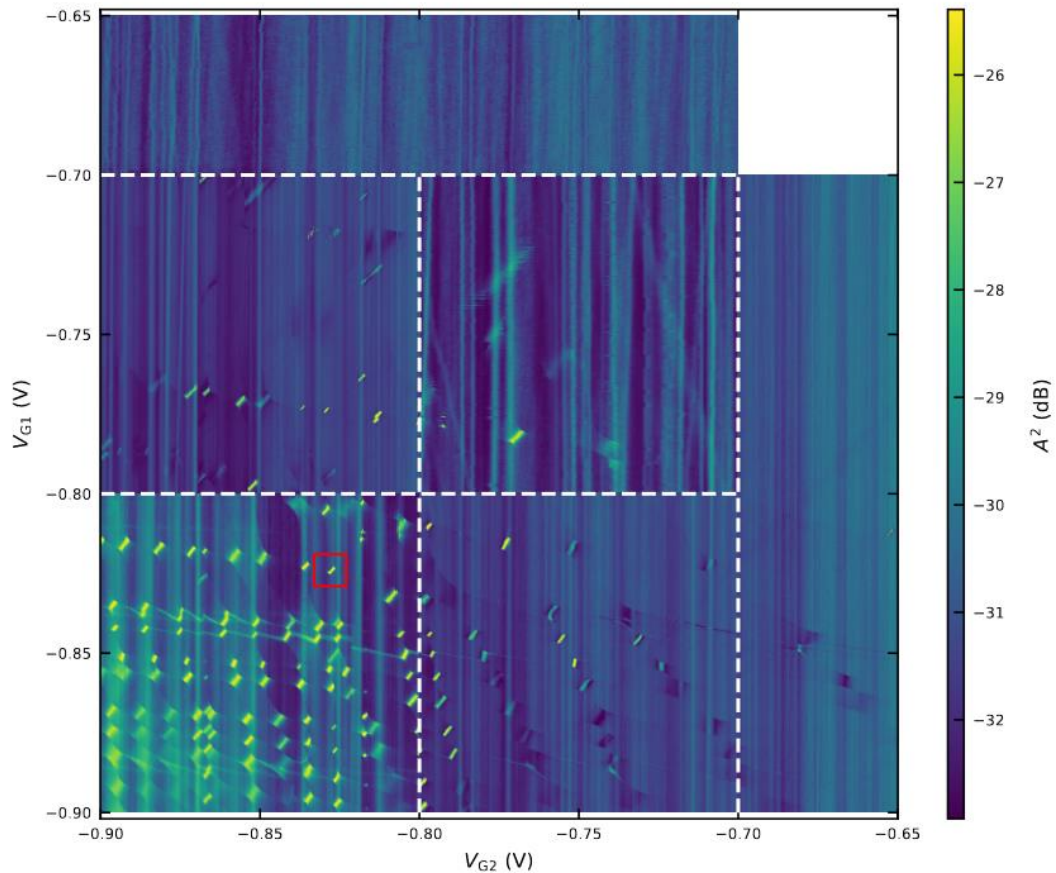


Resonator

C. Yu et. al., Appl. Phys. Lett. **118**, 054001 (2021)



Charge Stability Diagram



Charge-Photon Coupling Characterisation

$$\chi_c = g_c^2 d_{01}^2 (p_0 - p_1) \left(\frac{1}{\Delta} + \frac{1}{\omega_c + \omega_r} \right)$$

$$\hbar\omega_c = \sqrt{\varepsilon^2 + 4t_c^2}$$

$$d_{01} = \frac{2t_c}{\sqrt{\varepsilon^2 + 4t_c^2}}$$

Zero detuning:

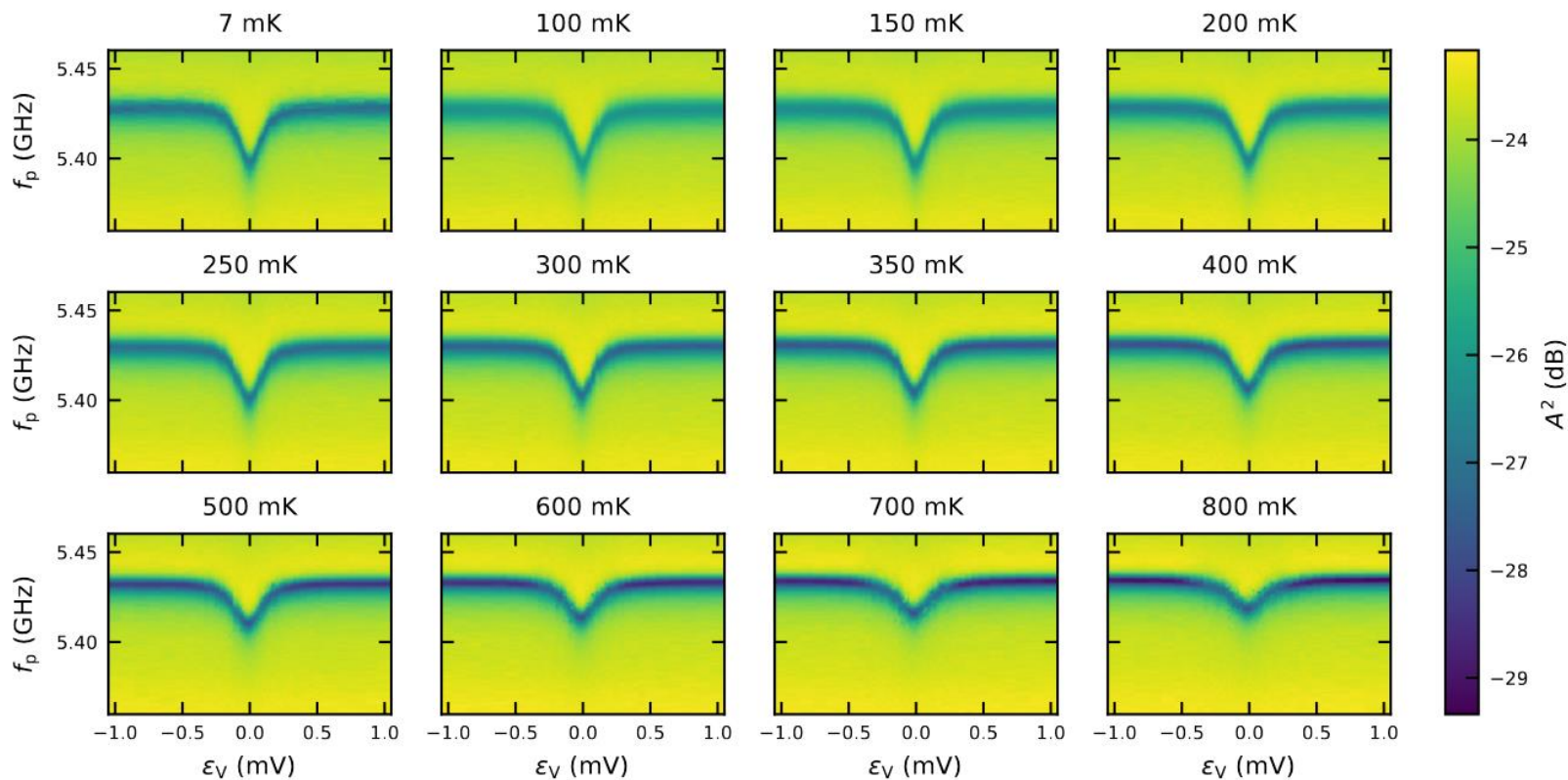
$$\chi_c = 2g_c^2 \frac{\omega_c}{\omega_c^2 - \omega_r^2} (p_0 - p_1)$$

$$p_1 = \frac{1}{1 + e^{\hbar\omega_c/(k_B T)}},$$

$$p_0 = 1 - p_1,$$

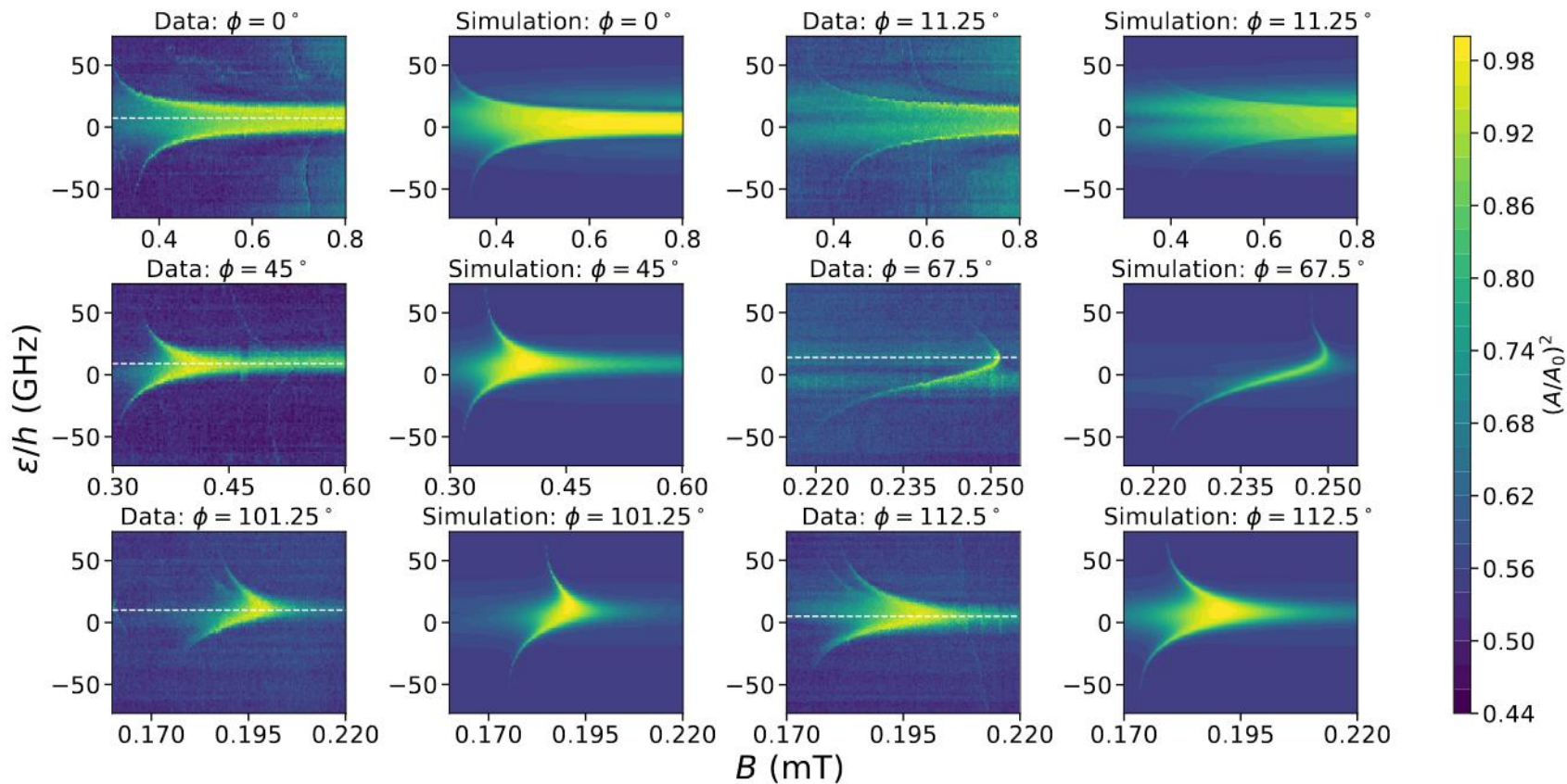


Detuning Field Maps



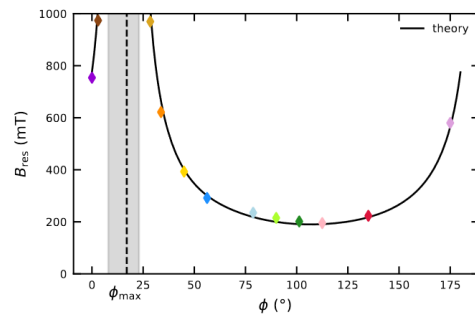
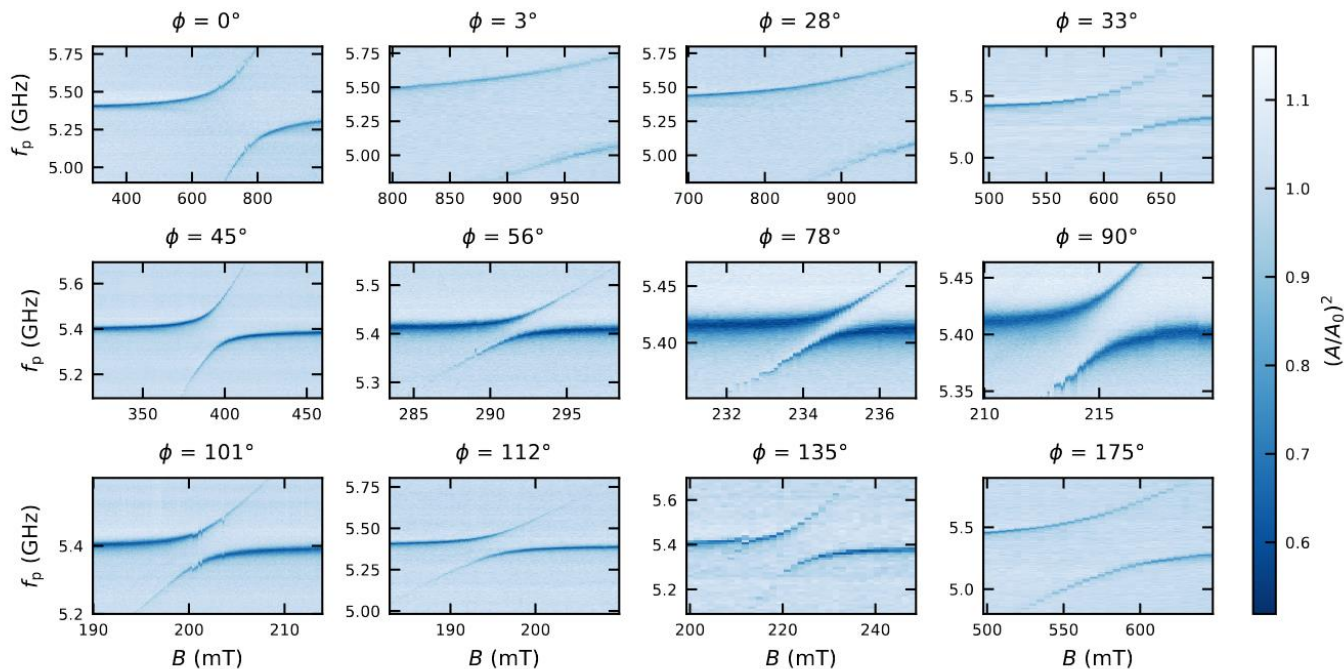
Angular Dependence Spin-Photon Coupling

Resonance Field

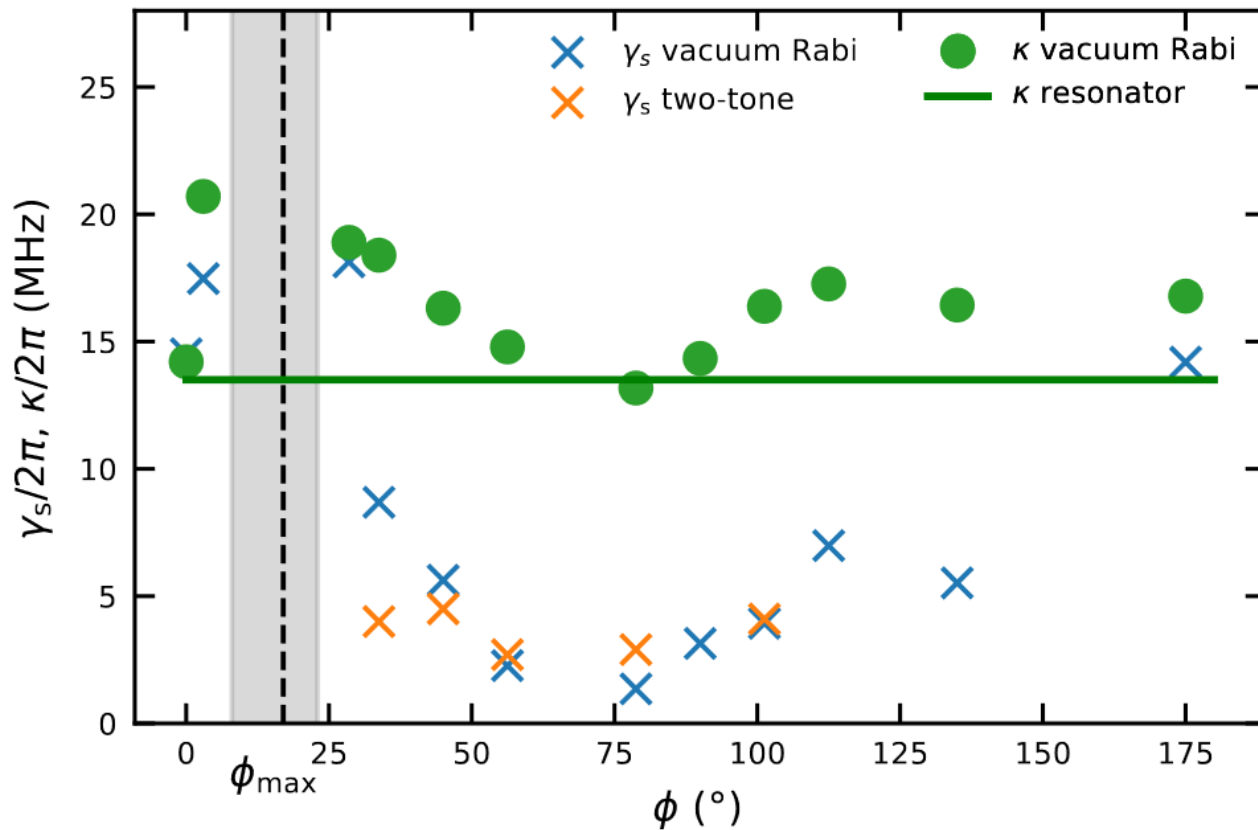


Angular Dependence Spin-Photon Coupling

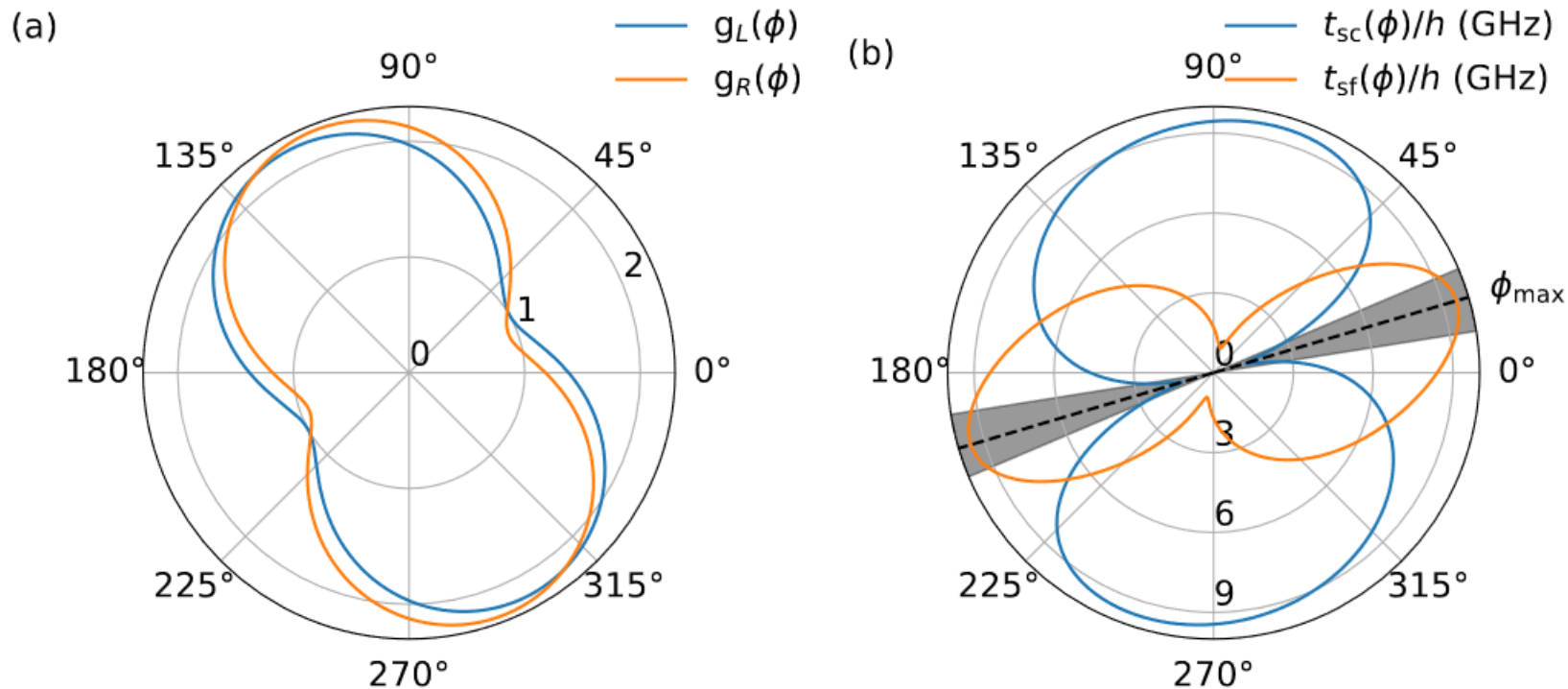
Resonance Field



Angular Dependence of γ_S and κ



Anisotropy of g-Factors and Tunnel Couplings



Theory of Angular Dependence Spin-Photon Coupling

$$H_{\text{tunnel}} = t_0 \tau_x - (\mathbf{t} \cdot \boldsymbol{\sigma}) \tau_y \quad t_c = \sqrt{t_0^2 + |\mathbf{t}|^2}$$

$$t_0 = t_c \cos \eta \quad \mathbf{t} = t_c \sin \eta \mathbf{n}_{\text{so}}$$

$$\begin{aligned} H_{\text{DD}} &= H_\varepsilon + H_{\text{Zeeman}} + H_{\text{tunnel}} \\ &= -\frac{\varepsilon}{2} \tau_z + \frac{1}{2} \mu_B \tau_L \left(\boldsymbol{\sigma} \cdot \tilde{\mathbf{g}}_L V_L^\dagger \mathbf{B} \right) + \frac{1}{2} \mu_B \tau_R \left(\boldsymbol{\sigma} \cdot \tilde{\mathbf{g}}_R V_R^\dagger \mathbf{B} \right) + t_0 \tau_x - \tau_y (\mathbf{t} \cdot \boldsymbol{\sigma}) \end{aligned}$$

Transform Hamiltonian with diagonalization of Zeeman term:

$$H'_{\text{DD}}(\phi) = T(\phi)^\dagger H_{\text{DD}} T(\phi) = -\frac{\varepsilon}{2} \tau_z + \tau_L \frac{1}{2} \mathbf{g}_L^*(\phi) \mu_B B \sigma_z + \tau_R \frac{1}{2} \mathbf{g}_R^*(\phi) \mu_B B \sigma_z + t_{\text{sc}}(\phi) \tau_x - t_{\text{sf}}(\phi) \tau_y \sigma_y$$



Theory of Angular Dependence Spin-Photon Coupling

$$g_s = g_c |\langle -\uparrow | \tau_z | -\downarrow \rangle| \text{ with } g_c = \frac{1}{2\hbar} \alpha \beta_2 e V_{zpf}$$

When average Zeeman energy for both dots is $\ll 2t_c$:

$$g_s = g_c \frac{\bar{E}_Z t_{sf}}{2t_c^2}$$

Transform Hamiltonian with diagonalization of Zeeman term (assuming left and right g-matrices are the same):

$$t_{sf} = t_c \sin \eta |\mathbf{n}_l \times \mathbf{n}_{so}|$$

Introduce Effective Spin-Orbit Field:

$$\mu_B g \mathbf{B}_{so} = t_c \sin \eta \mathbf{n}_{so}$$

$$g_s = g_c \frac{\mu_B^2}{2t_c^2} |(\mathbf{g}\mathbf{B}) \times (\mathbf{g}\mathbf{B}_{so})|$$

